



SamHop Microelectronics Corp.



SP2107

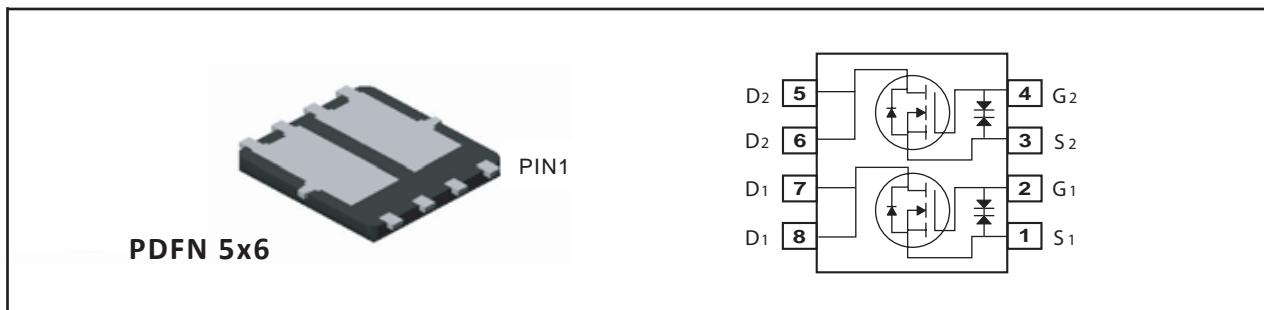
Ver 1.0

Dual N-Channel Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
VDSS	ID	RDS(ON) (Ω) Max
100V	1.2A	0.8 @ VGS=10V
		0.93 @ VGS=4.5V

FEATURES

- Super high dense cell design for low RDS(ON).
- Rugged and reliable.
- Surface Mount Package.
- ESD Protected.



ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter		Limit	Units
V_{DS}	Drain-Source Voltage		100	V
V_{GS}	Gate-Source Voltage		± 20	V
I_D	Drain Current-Continuous ^a	$T_A=25^\circ\text{C}$	1.2	A
		$T_A=70^\circ\text{C}$	1	A
I_{DM}	-Pulsed ^b		5	A
E_{AS}	Single Pulse Avalanche Energy ^d		2.25	mJ
P_D	Maximum Power Dissipation ^a	$T_A=25^\circ\text{C}$	2.5	W
		$T_A=70^\circ\text{C}$	1.6	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range		-55 to 150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	50	$^\circ\text{C/W}$
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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BVDSS	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	100			V
Idss	Zero Gate Voltage Drain Current	$V_{DS}=80V, V_{GS}=0V$			1	μA
IGSS	Gate-Body Leakage Current	$V_{GS} = \pm 20V, V_{DS}=0V$			± 10	μA
ON CHARACTERISTICS						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	1	2.1	3	V
RDS(ON)	Drain-Source On-State Resistance	$V_{GS}=10V, I_D=0.6A$		0.64	0.8	ohm
		$V_{GS}=4.5V, I_D=0.5A$		0.69	0.93	ohm
g _{FS}	Forward Transconductance	$V_{DS}=10V, I_D=0.6A$		2		S
DYNAMIC CHARACTERISTICS ^c						
C _{ISS}	Input Capacitance	$V_{DS}=25V, V_{GS}=0V$ $f=1.0MHz$		194		pF
C _{OSS}	Output Capacitance			26		pF
C _{RSS}	Reverse Transfer Capacitance			17		pF
SWITCHING CHARACTERISTICS ^c						
t _{D(ON)}	Turn-On Delay Time	$V_{DD}=50V$ $I_D=0.6A$ $V_{GS}=10V$ $R_{GEN}=6\text{ ohm}$		19.2		ns
t _r	Rise Time			19		ns
t _{D(OFF)}	Turn-Off Delay Time			172		ns
t _f	Fall Time			45		ns
Q _g	Total Gate Charge	$V_{DS}=50V, I_D=0.6A, V_{GS}=10V$		3.9		nC
Q _{gs}	Gate-Source Charge	$V_{DS}=50V, I_D=0.6A,$ $V_{GS}=10V$		1		nC
Q _{gd}	Gate-Drain Charge			1.1		nC
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
V _{SD}	Diode Forward Voltage	$V_{GS}=0V, I_S=1A$		0.86	1.2	V

Notes

- a.Surface Mounted on FR4 Board, $t < 10\text{sec}$.
- b.Pulse Test:Pulse Width $< 10\mu s$, Duty Cycle $< 1\%$.
- c.Guaranteed by design, not subject to production testing.
- d.Starting $T_J=25^\circ C, L=0.5\text{mH}, V_{DD} = 50V$. (See Figure13)

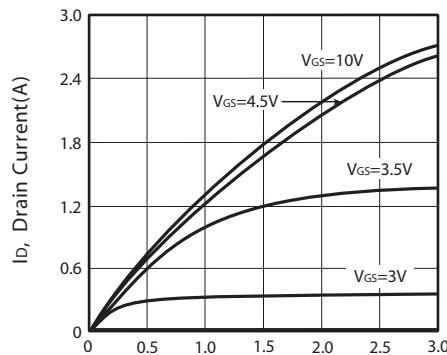


Figure 1. Output Characteristics

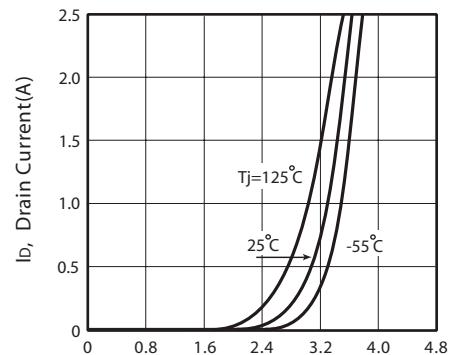


Figure 2. Transfer Characteristics

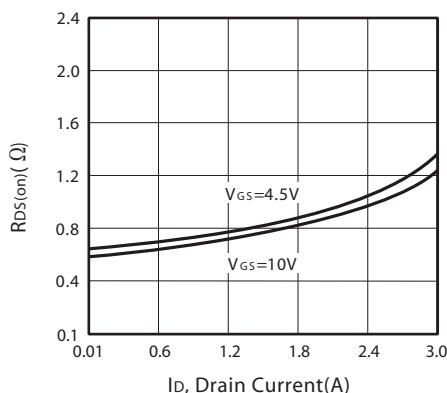


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

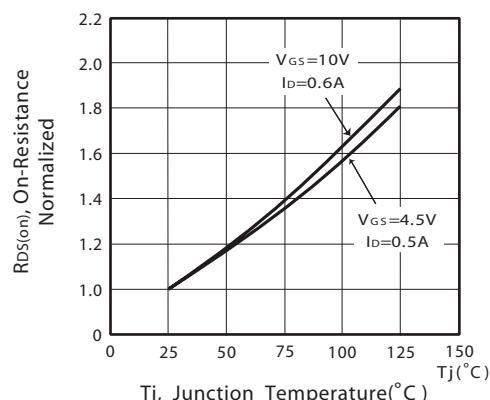


Figure 4. On-Resistance Variation with Drain Current and Temperature

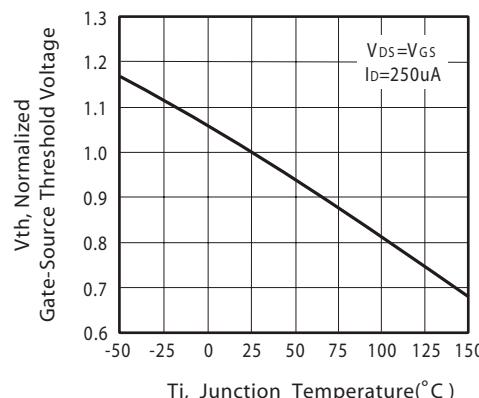


Figure 5. Gate Threshold Variation with Temperature

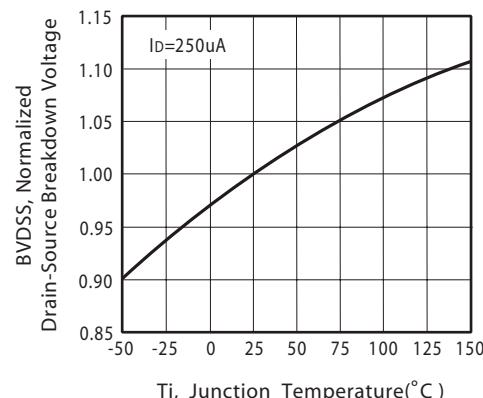
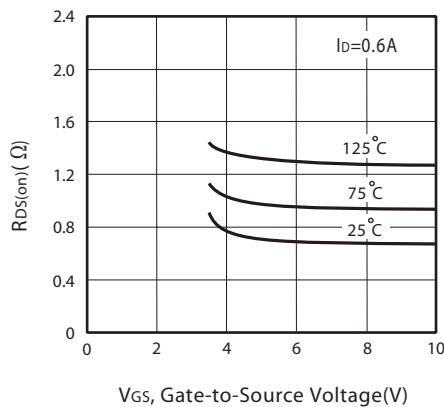
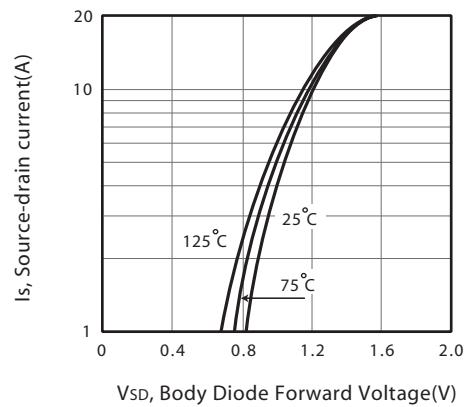


Figure 6. Breakdown Voltage Variation with Temperature



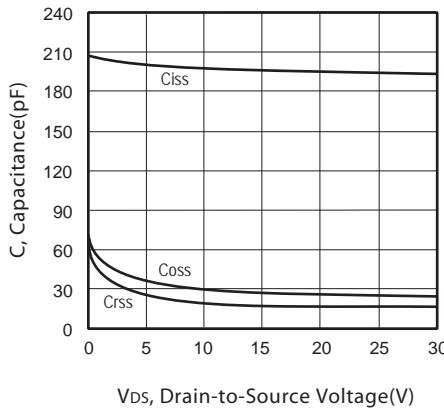
V_{GS}, Gate-to-Source Voltage(V)

Figure 7. On-Resistance vs. Gate-Source Voltage



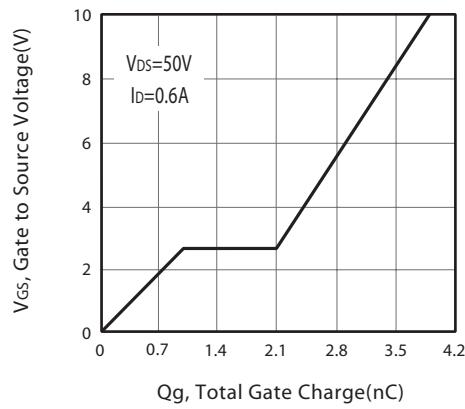
V_{SD}, Body Diode Forward Voltage(V)

Figure 8. Body Diode Forward Voltage Variation with Source Current



V_{DS}, Drain-to-Source Voltage(V)

Figure 9. Capacitance



Q_g, Total Gate Charge(nC)

Figure 10. Gate Charge

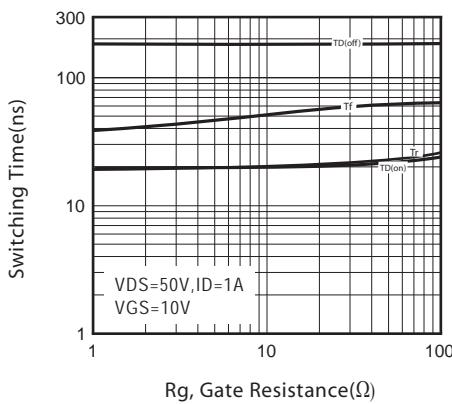


Figure 11. switching characteristics

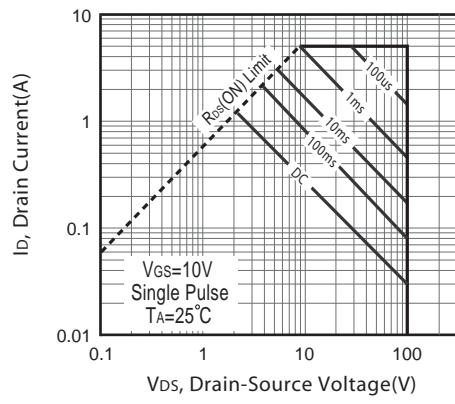
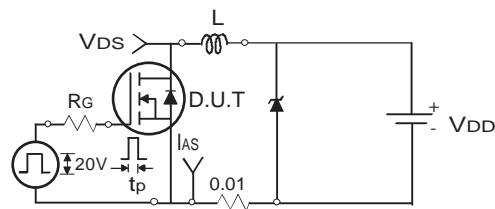
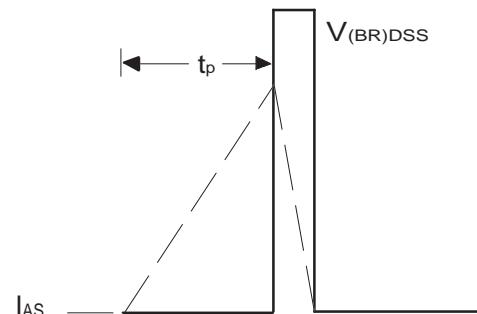


Figure 12. Maximum Safe Operating Area



Uncamped Inductive Test Circuit

Figure 13a.



Unclamped Inductive Waveforms

Figure 13b.

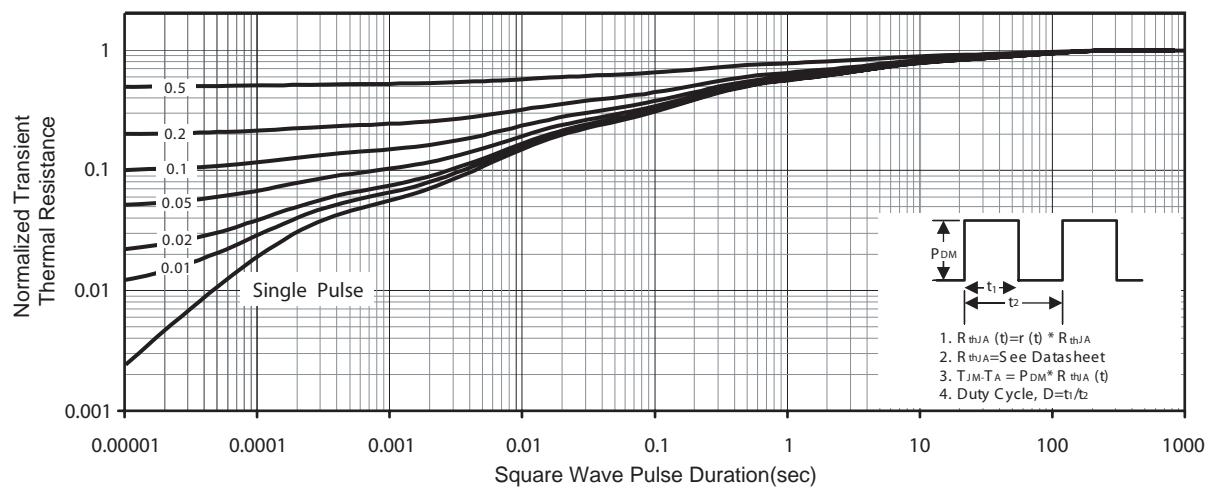
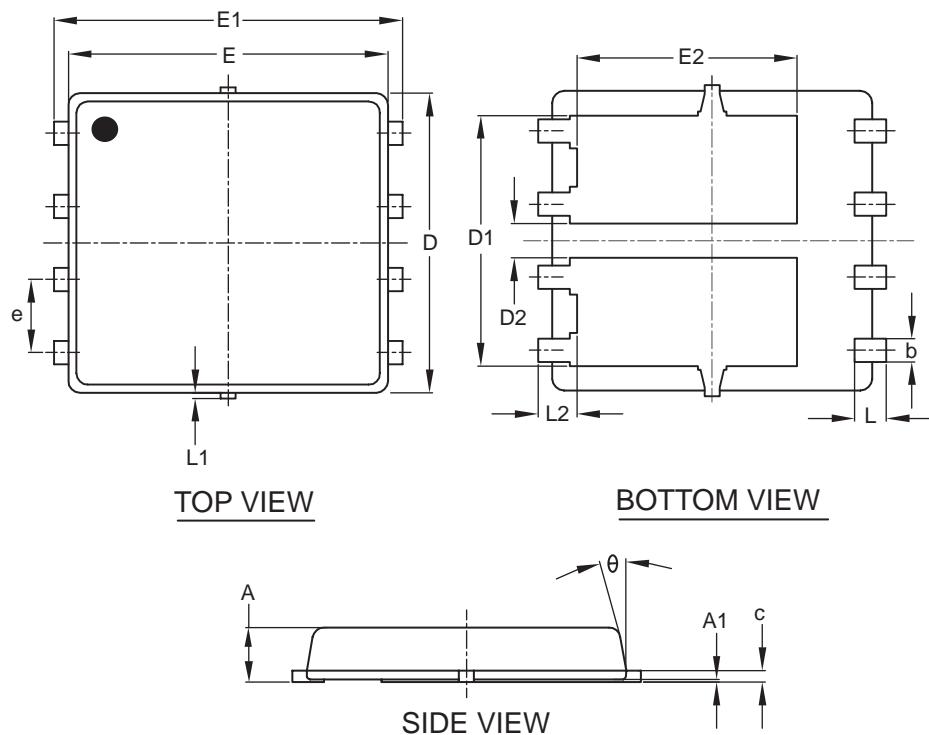


Figure 14. Normalized Thermal Transient Impedance Curve

PACKAGE OUTLINE DIMENSIONS

PDFN 5x6-8L



SYMBOLS	MILLIMETERS		
	MIN	NOM	MAX
A	0.85	0.95	1.00
A1	0.00	—	0.05
b	0.30	0.40	0.50
c	0.15	0.20	0.25
D	5.20 BSC		
D1	4.35 BSC		
D2	0.50	0.60	0.75
E	5.55 BSC		
E1	6.05 BSC		
E2	3.82 BSC		
e	1.27 BSC		
L	0.45	0.55	0.65
L1	0.00	—	0.15
L2	0.68 REF		
θ	0°	—	10°

TOP MARKING DEFINITION

PDFN 5x6-8L

